

/ Descriptions

TO-251 N MOS N-CHANNEL MOSFET in a TO-251 Plastic Package.

/ Features

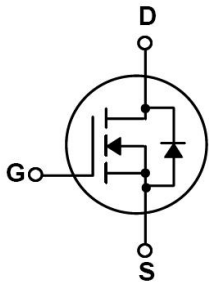
Low gate charge, low crss, fast switching.

/ Applications

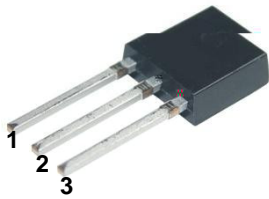
DC/DC

These devices are well suited for high efficiency switching DC/DC converters and switch mode power supplies.

/ Equivalent Circuit



/ Pinning



PIN1 G PIN 2 D PIN 3 S

/ h_{FE} Classifications & Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

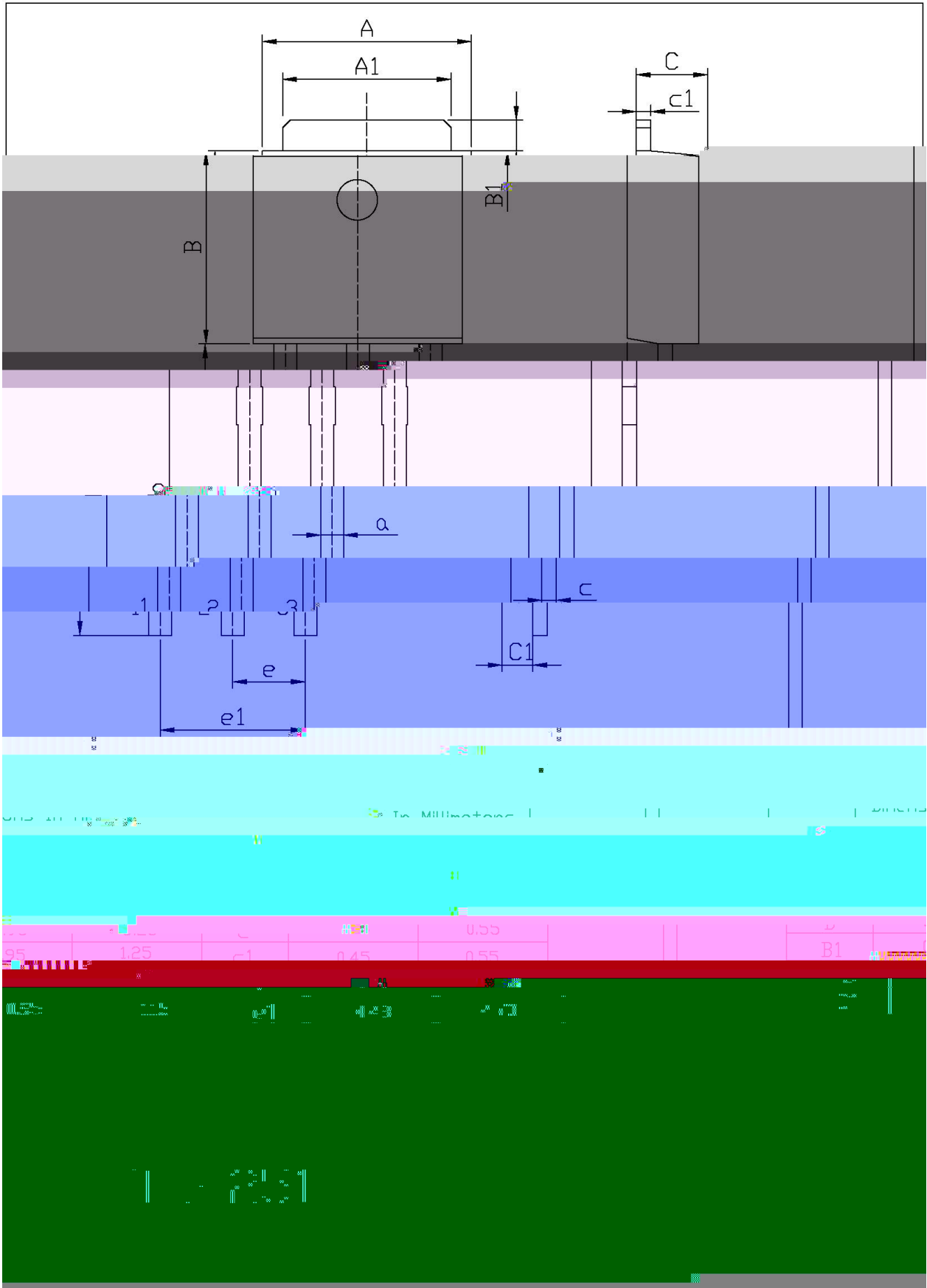
| Parameter | Symbol | Rating | Unit |
|--|----------------|------------|------|
| Drain-Source Voltage | V_{DSS} | 500 | V |
| Drain Current | $I_D(T_C=25)$ | 5 | A |
| Drain Current | $I_D(T_C=100)$ | 2.8 | A |
| Drain Current - Pulsed | I_{DM} | 16 | A |
| Gate-Source Voltage | V_{GSS} | ±30 | V |
| Avalanche Current | I_{AR} | 4 | A |
| Single Pulsed Avalanche Energy | E_{AS} | 300 | mJ |
| Repetitive Avalanche Energy | E_{AR} | 4.8 | mJ |
| Power Dissipation ($T_A=25$) | P_D | 2.5 | W |
| Power Dissipation ($T_C=25$) | P_D | 45 | |
| Junction and Storage Temperature Range | T_{stg} | -55 to 150 | |

/ Electrical Characteristics(Ta=25)

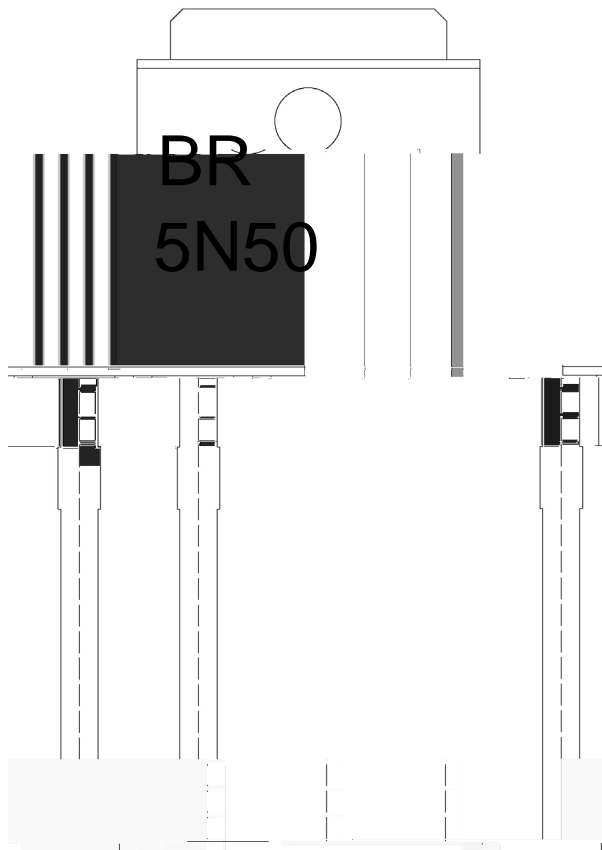
| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|------------------------------------|--------------|--------------------------------------|-----|------|------|------|
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V$ $I_D=250$ A | 500 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=500V$ $V_{GS}=0V$ | | | 1 | A |
| | | $V_{DS}=400V$ $T_C=125$ | | | 10 | A |
| Gate-Body Leakage Current, Forward | I_{GSS} | $V_{GS}=\pm 30V$ $V_{DS}=0V$ | | | ±0.1 | A |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}$ $I_D=250$ A | 2 | | 4 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}=10V$ $I_D=2.5A$ | | 1.14 | 1.4 | |
| Forward Transconductance | g_{FS} | $V_{DS}=40V$ $I_D=2A$ | | 5.2 | | S |
| Drain-Source Diode Forward Voltage | V_{SD} | $V_{GS}=0V$ $I_S=5A$ | | | 1.4 | V |
| Input Capacitance | C_{iss} | $V_{DS}=25V$ $V_{GS}=0V$ $f=1MHz$ | | 480 | 625 | pF |
| Output Capacitance | C_{oss} | | | 80 | 105 | |
| Reverse Transfer Capacitance | C_{rss} | | | 15 | 20 | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=250V$ $I_D=5A$ $R_G=25$ | | 12 | 35 | ns |
| Turn-On Rise Time | t_r | | | 46 | 100 | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 50 | 110 | |
| Turn-Off Fall Time | t_f | | | 48 | 105 | |

/ Electrical Characteristic Curve

/ Package Dimensions



/ Marking Instructions



BR

5N 50

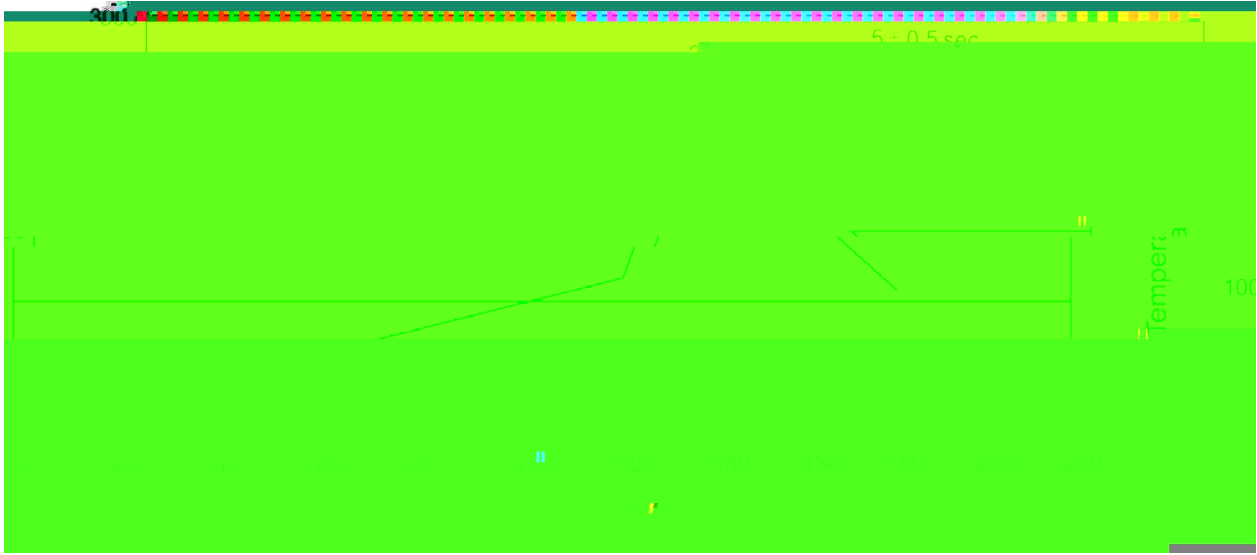
Note:

BR: Company Code

5N 50: Product Type.

****: Lot No. Code, code change with Lot No.

() / Temperature Profile for Dip Soldering(Pb-Free)



- | | | | | | | |
|---|-------|-----|-----------|--------|---|--------------------------------------|
| 1 | 25 | 150 | 60 | 90sec; | Note: | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 255±5 | | 5±0.5sec; | | 2.Peak Temp.:255±5 , Duration:5±0.5sec. | |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. | |

/ Resistance to Soldering Heat Test Conditions

270±5 10±1 sec. Temp.:270±5 Time:10±1 sec

/ Packaging SPEC.

/ BULK

| Package Type | Units | | | | | Dimension (unit mm ³) | | |
|--------------|-------|--|--|--|--|-----------------------------------|--|--|
| | | | | | | | | |
| | | | | | | | | |

/ TUBE

| Package Type | Units | Dimension (unit mm ³) |
|--------------|-------|-----------------------------------|
| | | |